

T495D477K006AHA150

T495 Auto, Tantalum, MnO2 Tantalum, Commercial Grade, 470 uF, 10%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 150 mOhms, 3.1 mm, 2817 / 7343



Click [here](#) for the 3D model.

General Information

Series	T495 Auto
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200
Features	Low ESR, Automotive
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
Qualifications	AEC-Q200
Typical Component Weight	446.84 mg

Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.6mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Specifications

Capacitance	470 uF
Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	12% 120Hz 25C
Failure Rate	N/A
ESR	150 mOhms (100kHz 25C)
Ripple Current	1000 mA (rms, 100kHz 25C), 900 mA (rms, 85C), 400 mA (rms, 125C)
Leakage Current	29.6 uA (5min 25°C)

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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